

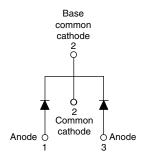
Vishay Semiconductors

Ultrafast Rectifier, 16 A FRED Pt®



T_J max.

Diode variation



175 °C

Common cathode

FEATURES

- Ultrafast recovery time
- Low forward voltage drop
- 175 °C operating junction temperature
- · Low leakage current
- AEC-Q101 qualified, meets JESD 201 class 2 whisker test







ROHS COMPLIANT HALOGEN FREE

PRODUCT SUMMARY					
Package	TO-220AB				
I _{F(AV)}	2 x 8 A				
V_{R}	400 V				
V _F at I _F	1.3 V				
t _{rr} (typ.)	24 ns				

DESCRIPTION/APPLICATIONS

FRED Pt® series are the state of the art ultrafast recovery rectifiers specifically designed with optimized performance of forward voltage drop and ultrafast recovery time.

The planar structure and the platinum doped life time control, guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, UPS, DC/DC converters as well as freewheeling diode in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Peak repetitive reverse voltage	V_{RRM}		400	V	
per leg			8		
Average rectified forward current total device	I _{F(AV)}	T _C = 155 °C, rated V _R	16	٨	
Non-repetitive peak surge current	I _{FSM}	T _C = 25 °C	100	Α	
Peak repetitive forward current	I _{FRM}	T _C = 155 °C, rated V _R , square wave, 20 kHz	16		
Operating junction and storage temperatures	T _J , T _{Stg}		- 65 to 175	°C	

ELECTRICAL SPECIFICATIONS PER LEG (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V _{BR} , V _R	Ι _R = 100 μΑ	400	-	-		
Forward voltage V _F		I _F = 8 A	-	1.19	1.3	V	
		I _F = 8 A, T _J = 150 °C	=	0.94	1.0		
Deverse leekees europt		$V_R = V_R$ rated	-	0.2	10		
Reverse leakage current I _R		T _J = 150 °C, V _R = V _R rated	-	20	500	μA	
Junction capacitance	C _T	V _R = 400 V	=	14	-	pF	
Series inductance	L _S	Measured lead to lead 5 mm from package body		8.0	-	nH	



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DYNAMIC RECOVERY CHARACTERISTICS PER LEG (T _J = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS	
		$I_F = 1.0 \text{ A}, dI_F/dt = 50 \text{ A/}\mu\text{A}, V_R = 30 \text{ V}$		-	35	-		
Reverse recovery time t _{rr}	t _{rr}	$I_F = 1.0 \text{ A}, dI_F/dt = 100 \text{ A/}\mu\text{A}, V_R = 30 \text{ V}$		-	24	-		
		T _J = 25 °C	I _F = 8 A dI _F /dt = 200 A/μs V _R = 200 V	-	43	-	ns	
		T _J = 125 °C		-	67	-		
Peak recovery current I _R	_	T _J = 25 °C		-	2.8	-	Α	
	IRRM	T _J = 125 °C		-	6.3	-		
Reverse recovery charge	Q_{rr}		T _J = 25 °C		=	60	-	nC
		T _J = 125 °C		-	210	-	IIC	

THERMAL MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T _J , T _{Stg}		- 65	-	175	°C
Thermal resistance, per leg	, _B		-	3.6	4	
junction to case per device	R _{thJC}		-	1.8	2]
Thermal resistance, junction to ambient	R _{thJA}	Typical socket mount	-	-	50	°C/W
Thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth and greased	-	0.5	-	
Mojaht			-	2.0	-	g
Weight			-	0.07	-	oz.
Mounting torque			6.0	_	12	kgf · cm
wounting torque			(5.0)	-	(10)	(lbf · in)
Marking device		Case style TO-220AB	16CTU04H			



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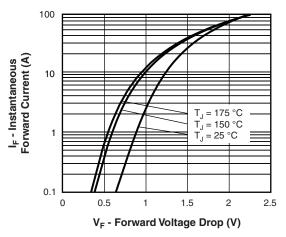


Fig. 1 - Typical Forward Voltage Drop Characteristics

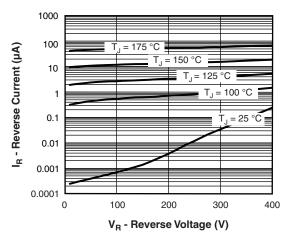


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

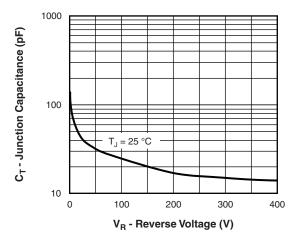


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

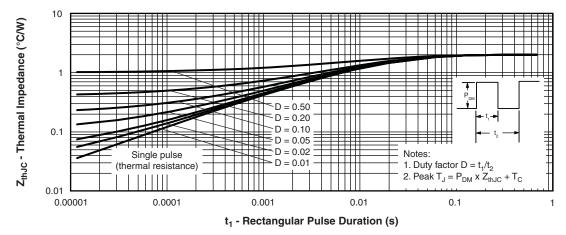


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics



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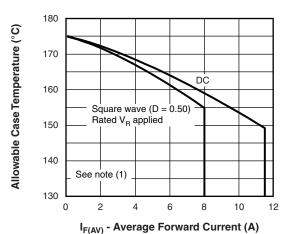
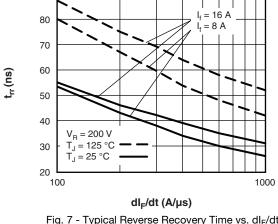


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current



90

Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

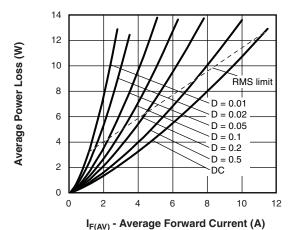


Fig. 6 - Forward Power Loss Characteristics

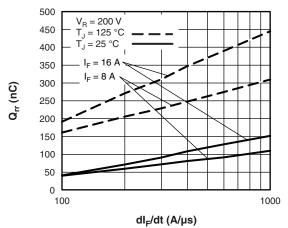
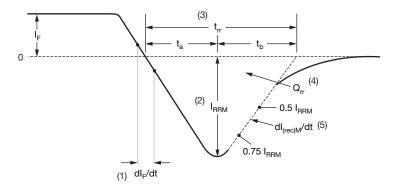


Fig. 8 - Typical Stored Charge vs. dl_F/dt

Note

(1) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; $Pd = Forward\ power\ loss = I_{F(AV)}\ x\ V_{FM}\ at\ (I_{F(AV)}/D)\ (see\ fig.\ 6);$ $Pd_{REV} = Inverse\ power\ loss = V_{R1}\ x\ I_R\ (1\ -\ D);\ I_R\ at\ V_{R1} = Rated\ V_R$

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- (1) dl_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) $\rm t_{rr}$ reverse recovery time measured from zero crossing point of negative going $\rm I_F$ to point where a line passing through 0.75 $\rm I_{RRM}$ and 0.50 $\rm I_{RRM}$ extrapolated to zero current.
- (4) $\rm Q_{rr}$ area under curve defined by $\rm t_{rr}$ and $\rm I_{RRM}$

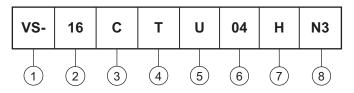
$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) $dI_{(rec)M}/dt$ - peak rate of change of current during t_b portion of t_{rr}

Fig. 1 - Reverse Recovery Waveform and Definitions

ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (16 = 16 A)

3 - Circuit configuration:

C = Common cathode

4 - Package:

T = TO-220

5 - Ultrafast recovery

6 - Voltage rating (04 = 400 V)

7 - H = AEC-Q101 qualified

8 - Environmental digit:

N3 = Halogen-free, RoHS-compliant and totally lead (Pb)-free

ORDERING INFO	RMATION (Example)		
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION
VS-16CTU04HN3	50	1000	Antistatic plastic tube

LINKS TO RELATED DOCUMENTS				
Dimensions <u>www.vishay.com/doc?95222</u>				
Part marking information	www.vishay.com/doc?95028			



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